

FRED Pt® Gen 4 Doubler Ultrafast Diode, 600 A (INT-A-PAK Power Modules)



PRIMARY CHARACTE	RISTICS
V_R	600 V
I _{F(AV)} at T _C	600 A at 25 °C
t _{rr} at 25 °C	150 ns
Туре	Modules - diode, FRED Pt®
Package	INT-A-PAK
Circuit configuration	Diode doubler circuit

FEATURES

- Gen 4 FRED Pt® dices technology
- · Ultrasoft reverse recovery characteristics
- Low I_{RRM} and reverse recovery charge
- Very low forward voltage drop
- 175 °C operating junction temperature
- UL approved file E78996 for application with maximum case temperature up to 140 °C
- Large creepage distances
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

Gen 4 FRED Pt technology, state of the art, ultra low V_F , soft switching optimized for IGBT F/W diode.

The minimized conduction loss, optimized storage charge, and low recovery current, minimized the switching losses and reduce the over dissipation in the switching element and snubbers.

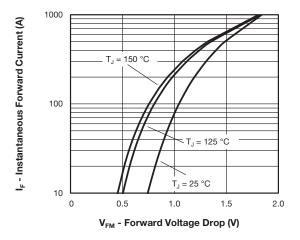
ABSOLUTE MAXIMUM RAT	INGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V_{R}		600	V	
Continuous forward current		T _C = 25 °C	771		
Continuous forward current	I _F	T _C = 63 °C	640	A	
Single pulse forward current	I _{FSM}	t_p = 10 ms, 50 Hz, sine half wave, initial T_J = 175 °C	4140		
Maximum navvar dissination	D	T _C = 25 °C	1923	W	
Maximum power dissipation	P_{D}	T _C = 90 °C	1090	- vv	
Operating junction temperature range	TJ		-40 to +175	°C	
Storage temperature range	T _{Stg}		-40 to +150]	
RMS insulation voltage	V _{INS}	50 Hz, circuit to base, all terminals shorted, t = 1 s	3500	V	

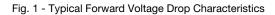
ELECTRICAL SPECIFICATION	DNS (T _J = 2	5 °C unless otherwise specif	ied)			
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	I _R = 500 μA	600	-	-	
		I _F = 300 A	-	1.305	-	
Forward voltage drop	V	I _F = 600 A	-	1.60	1.77	V
Forward voltage drop	V_{FM}	I _F = 300 A, T _J = 150 °C	-	1.08	-	
		I _F = 600 A, T _J = 150 °C	-	1.47	-	
Deverage legisless surrent		V _R = 600 V	-	13	1	μΑ
Reverse leakage current	I _{RM}	T _J = 150 °C, V _R = 600 V	-	3.2	-	mA



DYNAMIC RECOVERY	CHARAC	TERISTICS (T _J = 25	5 °C unless otherwise	specified	d)		
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
Payaraa raaayany timo	+	T _J = 25 °C		-	150	-	no
Reverse recovery time	t _{rr}	T _J = 125 °C		-	310	-	ns
Dook wasayan ayawant		T _J = 25 °C	I _F = 150 A dl/dt = 200 A/μs	-	14	-	^
Peak recovery current	Irr	T _J = 125 °C	$V_{R} = 400 \text{ V}$	-	33	-	A
Daylaraa raaaylari aharaa	0	T _J = 25 °C		-	1.65	-	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	7.03	-	μC

THERMAL -	MECHANI	MECHANICAL SPECIFICATIONS			
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum therm junction to case	,	R _{thJC}	DC operation	0.088	K/W
Typical thermal r		R _{thCS}	Mounting surface, flat, smooth and greased	0.035	
Mounting	to heat sink		A mounting compound is recommended and the		
torque ± 10 %	busbar		torque should be rechecked after a period of 3 hours to allow the spread of the compound.	4 to 6	Nm
Approximate we	iaht			200	g
Approximate we	igiit			7.1	oz.
Case style				INT-A-PAK	





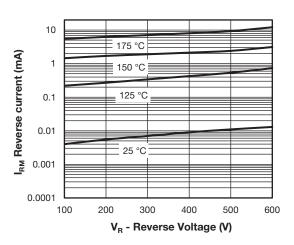


Fig. 2 - Typical Value of Reverse Current vs. Reverse Voltage

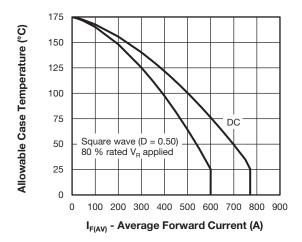


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current

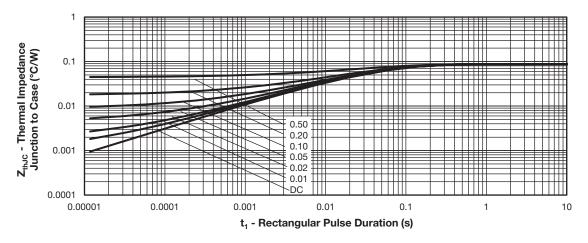


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

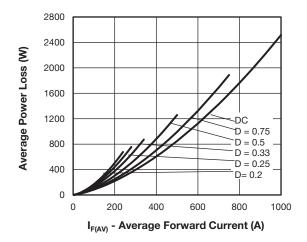


Fig. 5 - Forward Power Loss Characteristics

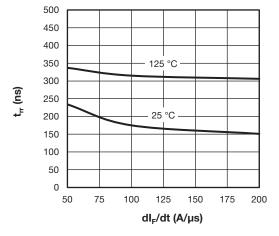


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt $I_{FM} = 150 \text{ A}, V_R = 400 \text{ V}$



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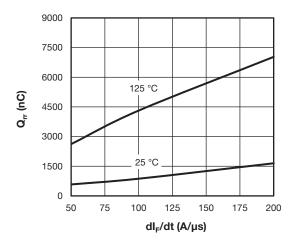


Fig. 7 - Typical Reverse Recovery Charge vs. dI_F/dt $I_{FM} = 150 \text{ A}, V_R = 400 \text{ V}$

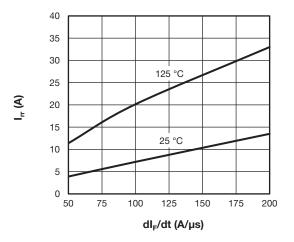
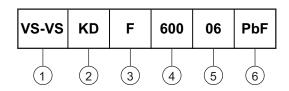


Fig. 8 - Typical Reverse Recovery Current vs. dI_F/dt I_{FM} = 150 A, V_R = 400 V

ORDERING INFORMATION TABLE

Device code



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- Circuit configuration: KD = doubler circuit

F = FRED Pt® ultrafast diode

- Current rating (600 = 600 A)

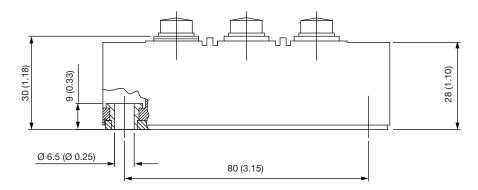
Voltage rating (06 = 600 V)

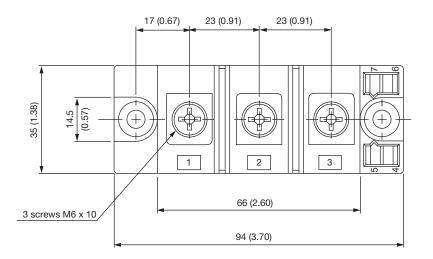
6 - PbF = lead (Pb)-free

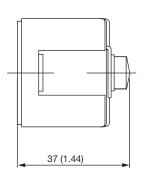
CIRCUIT CONFIGURATION			
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING	
Diode doubler circuit	KD	KD reversed polarity	



DIMENSIONS in millimeters (inches)



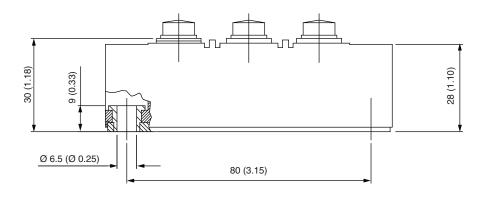


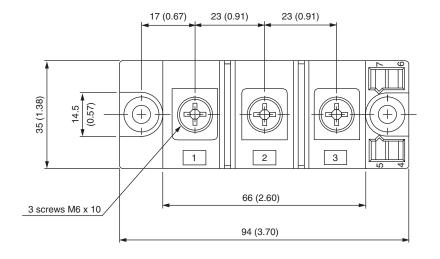


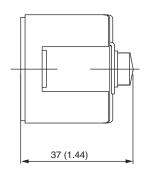


INT-A-PAK DBC

DIMENSIONS in millimeters (inches)









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